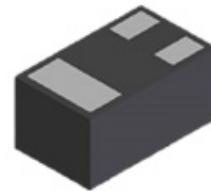
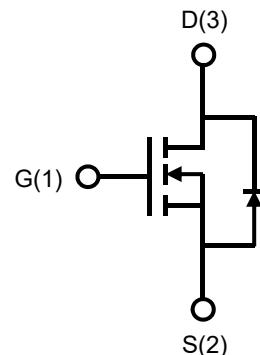


Description

The MOSFET provide the best combination of fast switching , low on-resistance and cost-effectiveness.

MOSFET Product Summary		
$V_{DS}(V)$	$R_{DS(on)}(m\Omega)$	$I_D(A)$
20	62 @ $V_{GS} = 4.5V$	2
	70 @ $V_{GS} = 2.5V$	


Bottom View

Circuit Diagram

Marking (Top View)

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Drain-source Voltage	V_{DS}	20	V
Gate-source Voltage	V_{GS}	± 12	V
Drain Current	I_D	2	A
Pulsed Drain Current	I_{DP}	6	A
Total Power Dissipation	P_D	300	mW
Channel to ambient	$R_{th(ch-a)}$	420	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C

N-Channel MOSFET

PNM3FD20V2

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = 1mA$	20	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$	-	-	± 0.1	μA
On Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.4	0.6	0.85	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 4.5V, I_D = 1.0A$	-	62	75	$m\Omega$
		$V_{GS} = 2.5V, I_D = 1.0A$	-	70	85	
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$	-	196	-	pF
Output Capacitance	C_{oss}		-	24	-	
Reverse Transfer Capacitance	C_{rss}		-	21	-	
Switching Parameters						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 6V, V_{GS} = 4.5V, R_G = 50\Omega, R_L = 12\Omega, I_D = 500mA$	-	6.6	-	ns
Turn-on Rise Time	t_r		-	70	-	
Turn-Off Delay Time	$t_{d(off)}$		-	13.5	-	
Turn-Off Fall Time	t_f		-	40	-	
Total Gate Charge	Q_g	$V_{DS} = 10V, I_D = 0.01A, V_{GS} = 4.5V$	-	2.3	-	nC
Gate-Source Charge	Q_{gs}		-	0.2	-	
Gate-Drain Charge	Q_{gd}		-	0.4	-	
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = 100mA$	-	0.7	1.0	V

Typical Characteristics

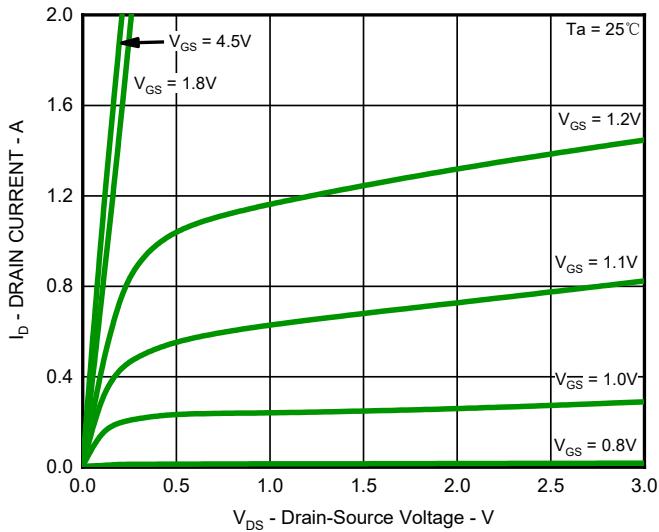


Fig.1 Output Characteristics

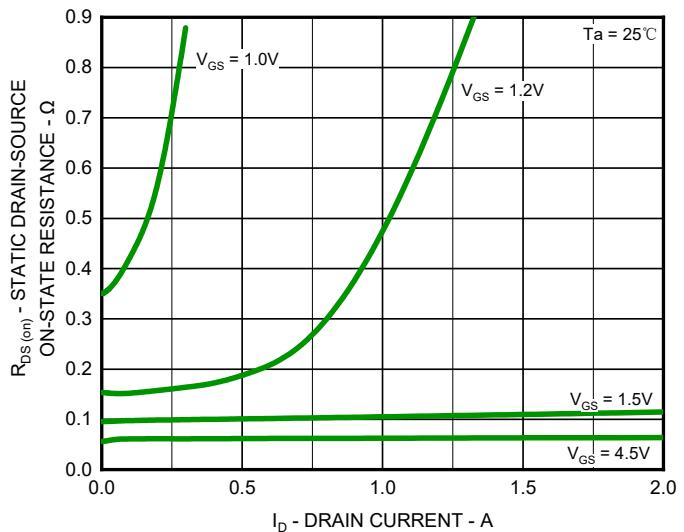
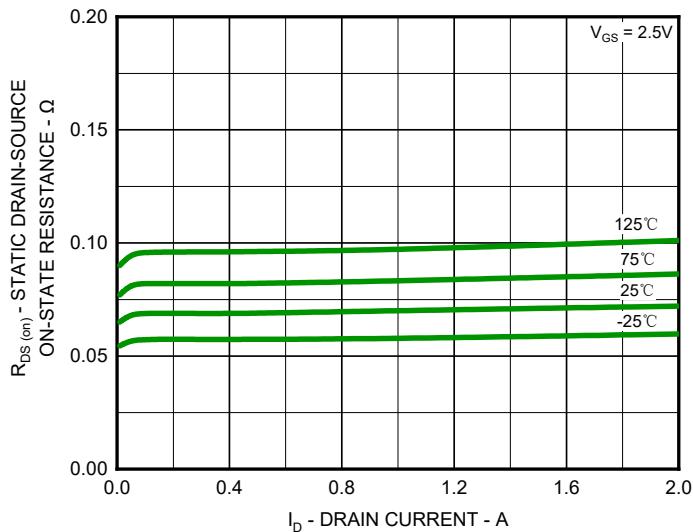
Fig.2 On-Resistance vs. Drain Current (I)

Fig.3 On-Resistance vs. Drain Current (II)

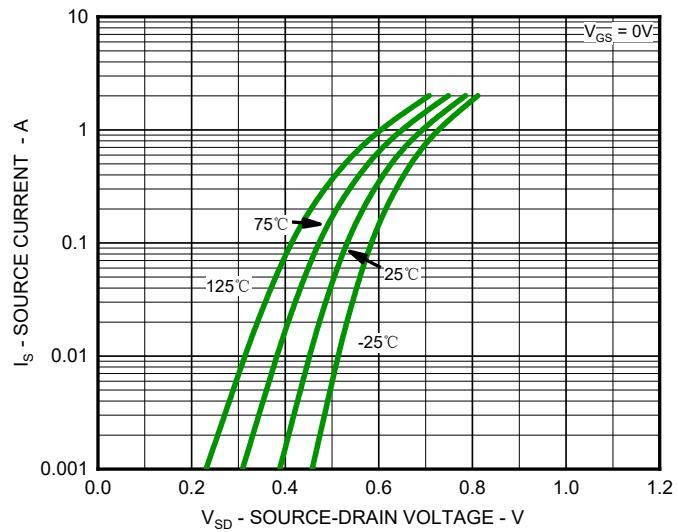


Fig.4 Diode Forward Voltage vs. Current

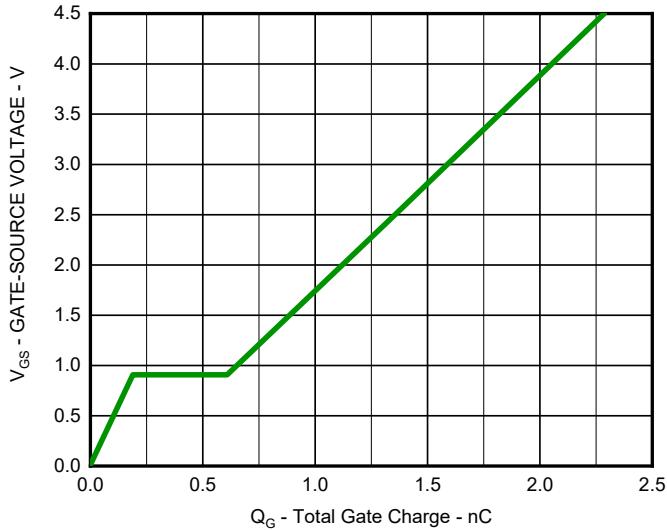


Fig.5 Gate Charge Characteristics

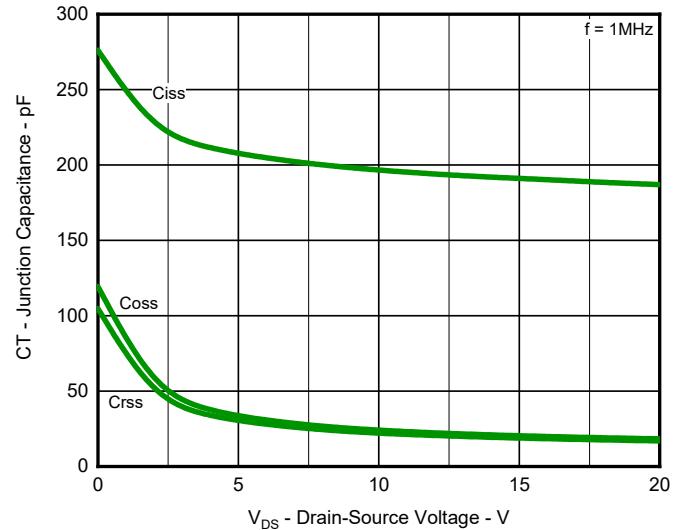
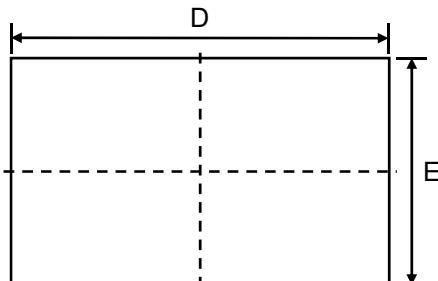


Fig.6 Typical Junction Capacitance

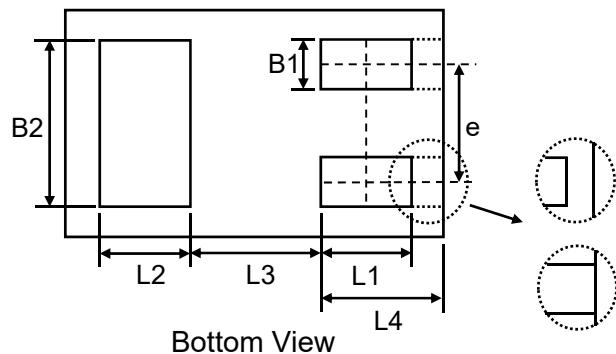
N-Channel MOSFET

PNM3FD20V2

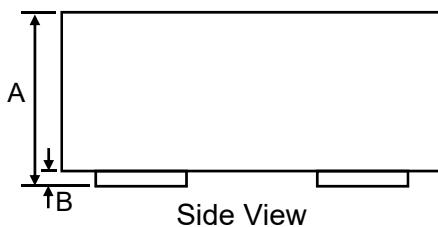
Product dimension (DFN1006-3L)



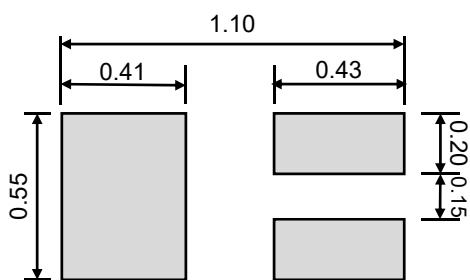
Top View



Bottom View



Side View



Suggested PCB Layout

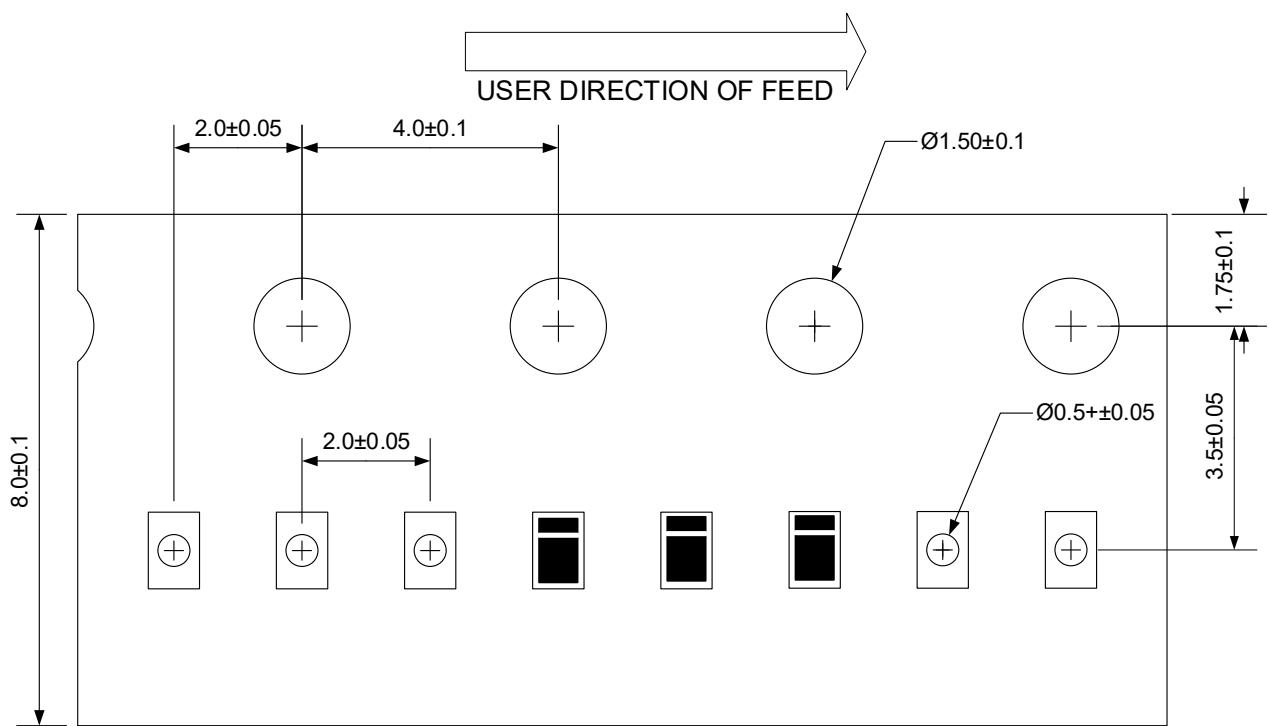
Unit:mm

Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	0.33	0.498	0.013	0.020
B	0.00	0.05	0.000	0.002
B1	0.10	0.20	0.004	0.008
B2	0.45	0.55	0.018	0.022
D	0.90	1.05	0.035	0.041
E	0.50	0.65	0.020	0.026
e	0.35		0.014	
L1	0.20	0.30	0.008	0.012
L2	0.20	0.30	0.008	0.012
L3	0.39		0.015	
L4	0.25	0.35	0.010	0.014

Ordering information

Device	Package	Reel	Shipping
PNM3FD20V2	DFN1006-3L(Pb-Free)	7"	10000 / Tape & Reel

Load with information



Unit:mm

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